
Emerging Nanomaterials and Devices

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Table of Contents

<i>Preface</i>	<i>iii</i>
Chapter 1 2D Nanomaterials and Devices	
(Invited) Highly Functional Graphene Nano-Electromechanical (GNEM) Devices for Advanced Switch and Sensor Applications <i>H. Mizuta, J. Sun, M. E. Schmidt, M. Muruganathan</i>	3
Enhancement of the Extent of In Situ Transfer-Free Few-Layer Graphene by Solid Carbon Source for Use in Gas Sensor Applications <i>D. Noll, U. Schwalke</i>	11
(Invited) Emerging Graphene Device Technologies <i>M. Östling, A. D. Smith, S. Vaziri, S. Sollami Delekta, J. Li, M. C. Lemme</i>	17
Titanium Carbide MXene Flakes as Novel 2D Metallic Solution-Processed Films <i>M. Mariano, O. Mashtalir, F. Antonio, W. H. Ryu, B. Deng, F. Xia, Y. Gogotsi, A. D. Taylor</i>	37
Theoretical Analysis and Experimental Optimization of Graphene/TMD Heterojunction Barristors <i>J. Shim, Y. H. Kim, J. H. Park</i>	43
Current Transport in Graphene/Copper Hybrid Nano Ribbon Interconnect: A First Principle Study <i>K. M. Mohsin, A. Srivastava, A. K. Sharma, C. Mayberry, M. S. Fahad</i>	49

Chapter 2 **Emerging Device and Circuit Applications**

Favorable Combination of Schottky Barrier and Junctionless Properties in Field-Effect Transistors for High Temperature Applications <i>T. A. Krauss, F. Wessely, U. Schwalke</i>	57
Evaluation of Different <i>High K</i> Materials for <i>In situ</i> Growth of Carbon Nanotubes <i>M. Keyn, T. A. Krauss, A. Kramer, U. Schwalke</i>	65
High-Performance Photodetectors Using Transition Metal Dichalcogenide (TMD)-based Hybrid Structures <i>S. H. Jo, J. H. Park</i>	73

Chapter 3 **Materials for Memory Applications**

(Invited) Compliance-Free Pulse Forming of Filamentary RRAM <i>P. Shrestha, D. M. Nminibapiel, J. H. Kim, H. Baumgart, K. P. Cheung, J. P. Campbell</i>	81
Impact of Etch Process on Hafnium Dioxide Based Nanoscale RRAM Devices <i>K. Beckmann, J. Holt, W. Olin-Ammentorp, J. Van Nostrand, N. Cady</i>	93
Resistance Switching in Individual Hydrogen Silsesquioxane (HSQ) Nanopillars <i>W. H. Ng, M. Buckwell, A. Mehonic, A. J. Kenyon</i>	101

Chapter 4 **Nanomaterials – Growth and Transfer**

(Invited) Epitaxial Oxides on Silicon for CMOS and Beyond <i>H. J. Osten</i>	109
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Chapter 5
Poster Session

Thermoelectric Properties of Highly Ordered Metal-Organic Framework Films <i>X. Chen, Z. Wang, P. Lin, K. Zhang, H. Baumgart, E. Redel, C. Wöll</i>	119
Enhanced Photocurrents in the Vertically Aligned Hybrid CdTe-Si One-Dimensional Nanostructures with High Surface Area <i>J. Lim, S. H. Hwang, H. Jung</i>	127
Wafer-Level Fabrication and Characterization of Amorphous Thin Films MoS ₂ Prepared by RF Magnetron Sputtering Technique <i>K. R. Gustavsen, K. A. Nygård, P. Honerød-Bentsen, K. Du, G. Liu, M. Tayyib, D. W. Breiby, K. Weibye, O. Nilsen, K. E. Aasmundevit, K. Wang</i>	131
Fabrication of a-C Semiconductor Nanoparticles for Quantum Dots Surface Emitting Laser Using High-Density Plasma in Localized Area <i>R. Kobayashi, Y. Nagata, K. Okafuji, S. Ohtomo, H. Naragino, K. Honda</i>	139
Development of Silicon and Carbon Based p-Type Amorphous Semiconductor Films with Optical Gap Variable for High-Efficiency Multi-Junction Solar Cells <i>H. Naragino, Y. Nagata, K. Okafuji, S. Ohtomo, Y. Shimizu, K. Honda</i>	153
Author Index	161